BLP8G10S-45P; Power LDMOS transistor Rev. 4 — 29 October 2018

AMPLEON

Product data sheet

Product profile

1.1 General description

The BLP8G10S-45P and BLP8G10S-45PG are dual path, 45 W LDMOS power transistors for base station applications at frequencies from 700 MHz to 1000 MHz.

Application performance Table 1.

Typical RF performance at T_{case} = 25 °C; I_{Da} = 224 mA in common source class-AB production circuit.

Test signal	f	V _{DS}	P _{L(AV)}	Gp	η _D	ACPR
	(MHz)	(V)	(W)	(dB)	(%)	(dBc)
2-carrier W-CDMA	960	28	2.5	20.8	19.8	-49 [<u>1]</u>

^[1] Test signal: 3GPP; test model 1; 64 DPCH; PAR = 8.4 dB at 0.01% probability on CCDF; carrier spacing = 5 MHz; per section unless otherwise specified.

1.2 Features and benefits

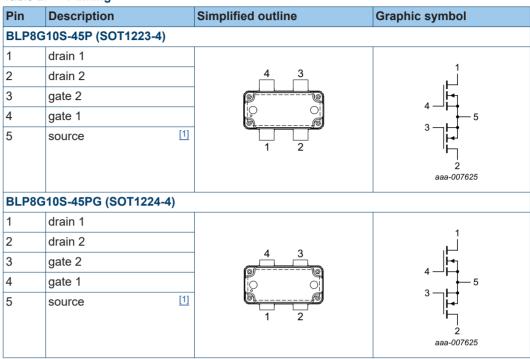
- High efficiency
- Excellent ruggedness
- Designed for broadband operation (700 MHz to 1000 MHz)
- Excellent thermal stability
- High power gain
- Integrated ESD protection
- For RoHS compliance see the product details on the Ampleon website

1.3 Applications

- W-CDMA
- LTE
- GSM

2. Pinning information

Table 2. Pinning



Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number	Package	Package				
	Name	Description	Version			
BLP8G10S-45P	-	plastic, heatsink small outline package; 4 leads (flat)	SOT1223-4			
BLP8G10S-45PG	-	plastic, heatsink small outline package; 4 leads	SOT1224-4			

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Min	Max	Unit
V_{DS}	drain-source voltage	-	65	V
V_{GS}	gate-source voltage	-0.5	+13	V
T _{stg}	storage temperature	-65	+150	°C
Tj	junction temperature [1]	-	225	°C
T _{case}	case temperature [1]	-	150	°C

[1] Continuous use at maximum temperature will affect the reliability.

5. Thermal characteristics

Table 5. Thermal characteristics

Values specified for entire device.

Sym	nbol	Parameter	Conditions	Тур	Unit
R _{th(j} .	-case)	thermal resistance from junction to case	T _{case} = 85 °C; P _L = 5 W	0.85	K/W

6. Characteristics

Table 6. DC characteristics

 $T_{case} = 25 \,^{\circ}C$; per section unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{(BR)DSS}	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 0.4 \text{ mA}$	65	-	-	V
V _{GS(th)}	gate-source threshold voltage	V _{DS} = 10 V; I _D = 40 mA	1.5	1.9	2.3	V
I _{DSS}	drain leakage current	V _{GS} = 0 V; V _{DS} = 28 V	-	-	1.4	μΑ
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	-	7.3	-	A
I _{GSS}	gate leakage current	V _{GS} = 11 V; V _{DS} = 0 V	-	-	140	nA
9 _{fs}	forward transconductance	V _{DS} = 10 V; I _D = 2 A	-	3.0	-	S
R _{DS(on)}	drain-source on-state resistance	$V_{DS} = 10 \text{ V}; I_D = 1.4 \text{ A}$ $V_{GS} = V_{GS(th)} + 3.75 \text{ V}$	-	500	-	mΩ

Table 7. RF characteristics

Test signal: 2-carrier W-CDMA; PAR 8.4 dB at 0.01 % probability on CCDF; 3GPP test model 1; 1-64 DPCH; $f_1 = 952.5$ MHz; $f_2 = 957.5$ MHz; RF performance at $V_{DS} = 28$ V; $I_{Dq} = 224$ mA; $T_{case} = 25$ °C; per section in a class-AB production circuit unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
G _p	power gain	$P_L = 2.5 W$	20	20.8	-	dB
RLin	input return loss	P _L = 2.5 W	-	-18	-9	dB
η _D	drain efficiency	P _L = 2.5 W	18	19.8	-	%
ACPR	adjacent channel power ratio	P _L = 2.5 W	-	-49	-43	dBc

7. Test information

7.1 Ruggedness in class-AB operation

The BLP8G10S-45P and BLP8G10S-45PG are capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions: $V_{DS} = 28 \text{ V}$; $I_{Dq} = 224 \text{ mA}$; $P_L = 25 \text{ W}$; f = 728 MHz.

7.2 Impedance information

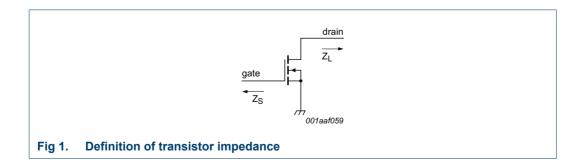
Table 8. Typical impedance

Measured load-pull data. Typical values per section unless otherwise specified.

f	Z _S [1]	Z _L [1][2]				
(MHz)	(Ω)	(Ω)				
BLP8G10S-45P						
720	11.6 – j12.9	5.44 + j6.34				
746	14.8 – j9.2	4.51 + j6.03				
757	15.3 – j4.6	4.23 + j6.15				
791	13.3 – j1.6	3.99 + j5.62				
820	6.5 – j1.1	3.87 + j5.37				
869	5.2 – j2.4	4.25 + j4.49				
894	4.4 – j3.0	3.69 + j4.89				
925	3.8 - j3.9	3.49 + j4.72				
942	3.6 – j4.2	3.06 + j4.46				
960	3.6 – j4.7	3.29 + j4.04				
BLP8G10S-45PG	'					
720	13.2 – j7.7	4.34 + j5.10				
746	11.8 – j4.6	4.58 + j4.94				
757	10.4 – j3.7	4.50 + j5.34				
791	9.8 – j2.5	4.19 + j4.87				
869	5.0 - j4.0	4.27 + j3.42				
881	4.6 – j4.2	3.62 + j3.45				
894	4.2 – j4.7	3.77 + j3.29				
925	3.8 – j5.6	3.60 + j3.15				
942	3.7 – j5.8	3.29 + j2.89				
961	3.6 – j6.4	3.36 + j2.47				

^[1] Z_S and Z_L defined in Figure 1.

[2] Z_L is selected for maximum efficiency.



7.3 Test circuit

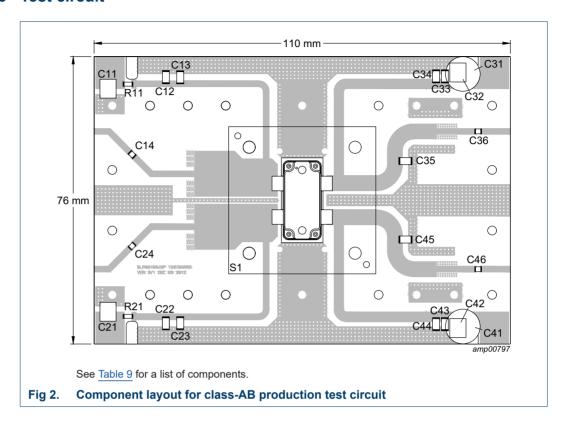


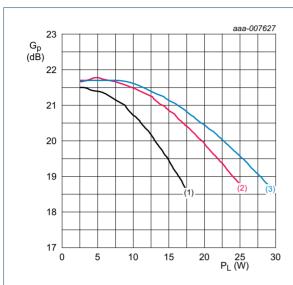
Table 9. List of components

For test circuit see Figure 2.

Component	Description	Value	Remarks
C11, C21, C32, C42	multilayer ceramic chip capacitor	10 μF, 50 V	
C12, C22, C33, C43	multilayer ceramic chip capacitor	1 μF, 50 V	
C13, C23, C34, C44	multilayer ceramic chip capacitor	43 pF	ATC100B
C14, C24, C36, C46	multilayer ceramic chip capacitor	43 pF	ATC100A
C31, C41	electrolytic capacitor	220 μF, 63 V	
C35, C45	multilayer ceramic chip capacitor	3.3 pF	ATC100B
R11, R21	chip resistor	10 Ω	Multi Comp SMD 1206
S1	socket	-	Johnstech

7.4 Graphical data

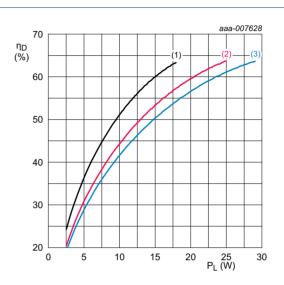
7.4.1 2-Carrier W-CDMA



 V_{DS} = 28 V; I_{Dq} = 224 mA; carrier spacing = 5 MHz; $f_{c} = 960 \text{ MHz}$

- (1) $V_{DS} = 24 \text{ V}$
- (2) $V_{DS} = 28 \text{ V}$
- (3) $V_{DS} = 32 V$

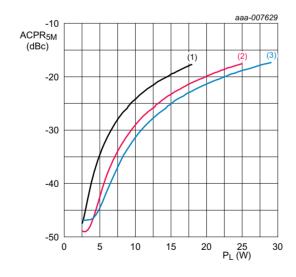
Power gain as a function of output power per Fig 3. section; typical values



 V_{DS} = 28 V; I_{Dq} = 224 mA; carrier spacing = 5 MHz; $f_c = 960 \text{ MHz}$

- (1) $V_{DS} = 24 \text{ V}$
- (2) $V_{DS} = 28 \text{ V}$
- (3) $V_{DS} = 32 V$

Drain efficiency as a function of output power Fig 4. per section; typical values



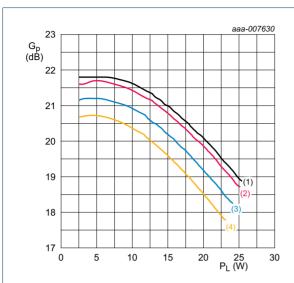
 V_{DS} = 28 V; I_{Dq} = 224 mA; carrier spacing = 5 MHz; f_c = 960 MHz

- (1) $V_{DS} = 24 \text{ V}$
- (2) $V_{DS} = 28 \text{ V}$
- (3) $V_{DS} = 32 V$

Adjacent channel power ratio (5 MHz) as a function of output power per section; typical values

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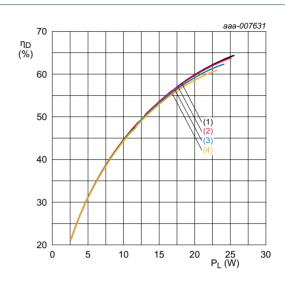
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 V_{DS} = 28 V; I_{Dq} = 224 mA; carrier spacing = 5 MHz; f_c = 960 MHz

- (1) T_{case} = 15 °C
- (2) T_{case} = 25 °C
- (3) $T_{case} = 55 \, ^{\circ}C$
- (4) $T_{case} = 85 \, ^{\circ}C$

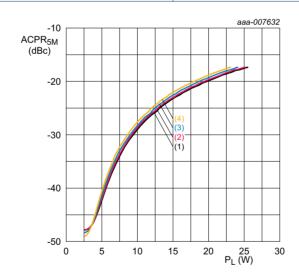
Fig 6. Power gain as a function of output power per section; typical values



 V_{DS} = 28 V; I_{Dq} = 224 mA; carrier spacing = 5 MHz; f_c = 960 MHz

- (1) $T_{case} = 15 \, ^{\circ}C$
- (2) $T_{case} = 25 \, ^{\circ}C$
- (3) $T_{case} = 55 \, ^{\circ}C$
- (4) T_{case} = 85 °C

Fig 7. Drain efficiency as a function of output power per section; typical values



 V_{DS} = 28 V; I_{Dq} = 224 mA; carrier spacing = 5 MHz; f_c = 960 MHz

- (1) T_{case} = 15 °C
- (2) T_{case} = 25 °C
- (3) $T_{case} = 55 \, ^{\circ}C$
- (4) $T_{case} = 85 \, ^{\circ}C$

Fig 8. Adjacent channel power ratio (5 MHz) as a function of output power per section; typical values

8. Package outline

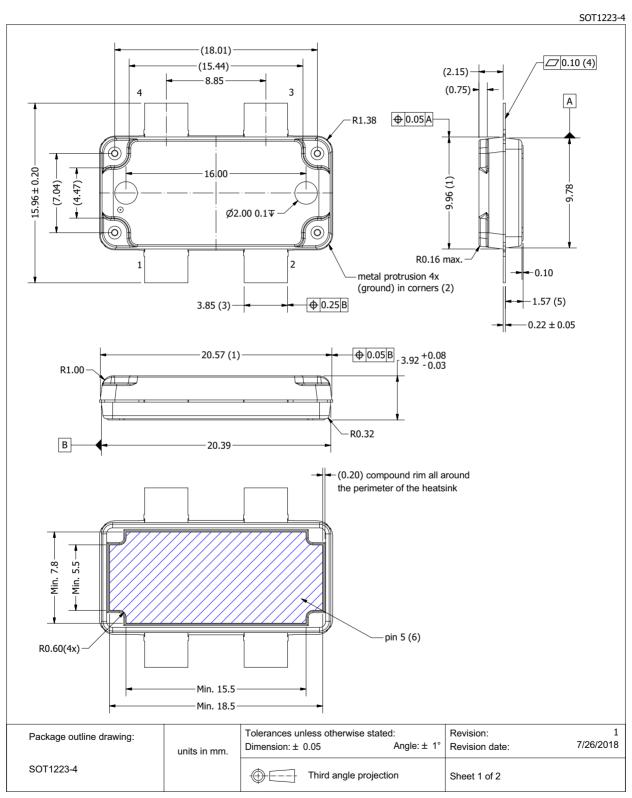


Fig 9. Package outline SOT1223-4 (sheet 1 of 2)

SOT1223-4

	Drawing Notes			
Items	Description			
	Dimensions are excluding mold protrusion. All areas located adjacent to the leads have a maximum mold protrusion of 0.25			
(1)	mm (per side) and max. 0.62 mm in length.			
	At all other areas the mold protrusion is maximum 0.15 mm per side. See also detail B.			
(2)	The metal protrusion (tie bars) might protrude the molding compound, max. protrusion 0.3 mm. (detail A).			
(3)	The lead dambar (metal) protrusions are not included. Add 0.14 mm max to the total lead dimension at the dambar location.			
(4)	The lead coplanarity over all leads is 0.1 mm maximum.			
(5)	Dimension is measured 0.5 mm from the edge of the top package body.			
(6)	The hatched area indicates the exposed metal heatsink.			
(7)	The leads and exposed heatsink are plated with matte Tin (Sn).			

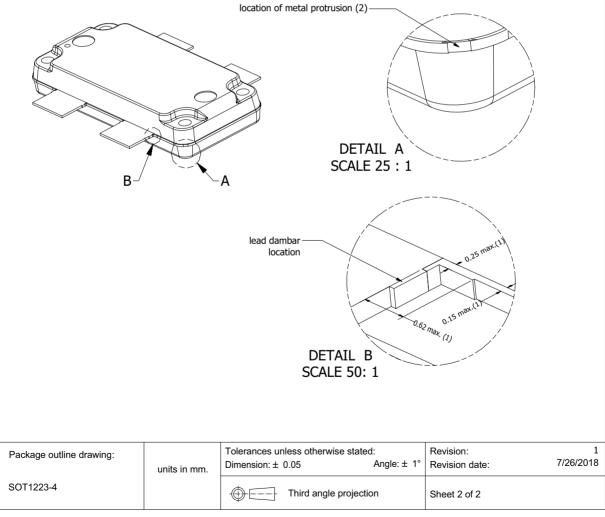


Fig 10. Package outline SOT1223-4 (sheet 2 of 2)

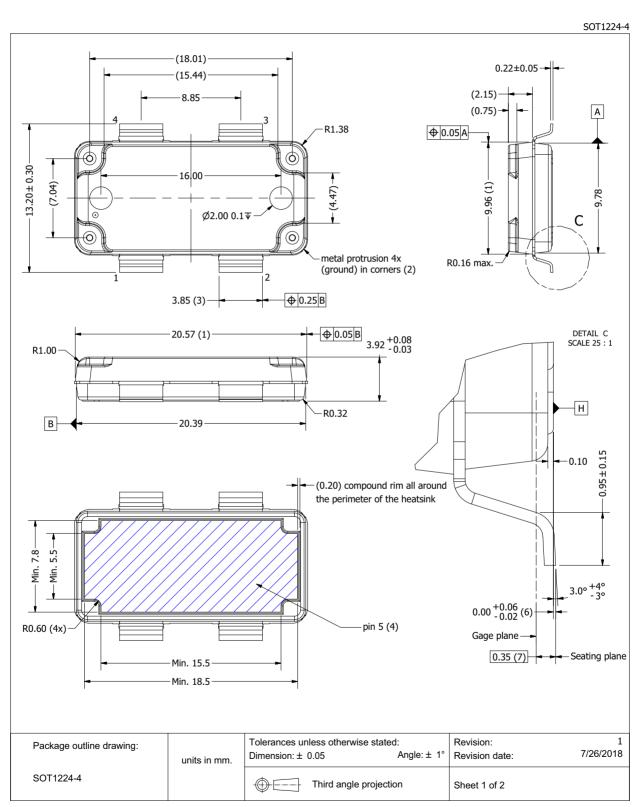


Fig 11. Package outline SOT1224-4 (sheet 1 of 2)

SOT1224-4

Drawing Notes				
Items	Description			
	Dimensions are excluding mold protrusion. All areas located adjacent to the leads have a maximum mold protrusion of 0.25			
(1)	mm (per side) and max. 0.62 mm in length. At all other areas the mold protrusion is maximum 0.15 mm per side. See also			
	detail B.			
(2)	The metal protrusion (tie bars) might protrude the molding compound, max. protrusion 0.3 mm. (detail A).			
(3)	The lead dambar (metal) protrusions are not included. Add 0.14 mm max to the total lead dimension at the dambar location.			
(4)	The hatched area indicated the exposed heatsink.			
(5)	The leads and exposed heatsink are plated with matte Tin (Sn).			
(C)	Dimension is measured with respect to the bottom of the heatsink Datum H. Positive value means that the bottom of the			
(6)	heatsink is higher than the bottom of the lead.			
(7)	Gage plane (foot length) to be measured from the seating plan.			

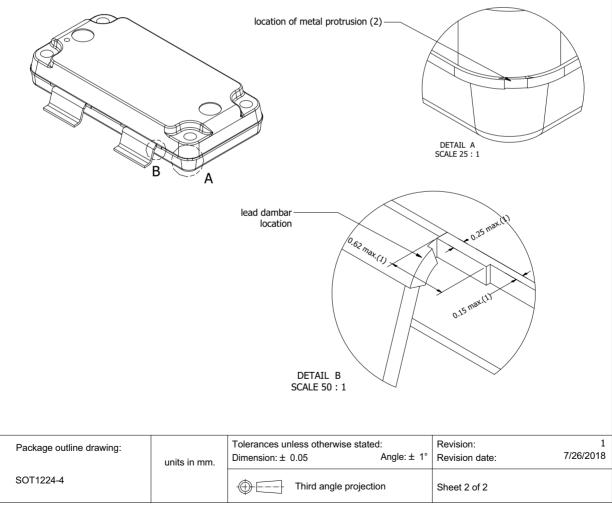


Fig 12. Package outline SOT1224-4 (sheet 2 of 2)

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Power LDMOS transistor

Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

Table 10. ESD sensitivity

ESD model	Class
Charged Device Model (CDM); According to ANSI/ESDA/JEDEC standard JS-002	C2A [1]
Human Body Model (HBM); According to ANSI/ESDA/JEDEC standard JS-001	1C [2]

- CDM classification C2A is granted to any part that passes after exposure to an ESD pulse of 500 V.
- HBM classification 1C is granted to any part that passes after exposure to an ESD pulse of 1000 V.

10. Abbreviations

Table 11. Abbreviations

Acronym	Description
3GPP	3rd Generation Partnership Project
CCDF	Complementary Cumulative Distribution Function
DPCH	Dedicated Physical CHannel
ESD	ElectroStatic Discharge
GSM	Global System for Mobile Communications
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
LTE	Long Term Evolution
PAR	Peak-to-Average Ratio
RoHS	Restriction of Hazardous Substances
SMD	Surface Mounted Device
VSWR	Voltage Standing-Wave Ratio
W-CDMA	Wideband Code Division Multiple Access

BLP8G10S-45P; BLP8G10S-45PG

Power LDMOS transistor

11. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLP8G10S-45P_8G10S-45PG v.4	20181029	Product data sheet	-	BLP8G10S-45P_8G10S-45PG v.3
Modifications:	Table 3 orFigure 2 oTable 10 oSection 8	n page 2: package ou n page 5: figure upd n page 12: table add	utline versions cha ated ded outline versions c	anged to SOT1223-4 and SOT1224-4 anged to SOT1223-4 and SOT1224-4 and SOT1224-4 anged from SOT1223-2 and
BLP8G10S-45P_8G10S-45PG v.3	20160108	Product data sheet	-	BLP8G10S-45P_8G10S-45PG v.2
BLP8G10S-45P_8G10S-45PG v.2	20150901	Product data sheet	-	BLP8G10S-45P_8G10S-45PG v.1
BLP8G10S-45P_8G10S-45PG v.1	20130725	Product data sheet	-	-

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12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
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